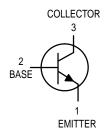
# **General Purpose Transistors NPN Silicon**



#### **MAXIMUM RATINGS**

Rating	Symbol	MPS2222	MPS2222A	Unit
Collector-Emitter Voltage	VCEO	30	40	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	60	75	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	6.0	Vdc
Collector Current — Continuous	IC	600		mAdc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	625 5.0		mW mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	PD	1.5 12		Watts mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	−55 to +150		°C

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage (I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 0)	MPS2222 MPS2222A	V(BR)CEO	30 40	_	Vdc
Collector-Base Breakdown Voltage (I <sub>C</sub> = 10 $\mu$ Adc, I <sub>E</sub> = 0)	MPS2222 MPS2222A	V(BR)CBO	60 75	_ _	Vdc
Emitter-Base Breakdown Voltage (IE = 10 $\mu$ Adc, IC = 0)	MPS2222 MPS2222A	V(BR)EBO	5.0 6.0	_ _	Vdc
Collector Cutoff Current (VCE = 60 Vdc, VEB(off) = 3.0 Vdc)	MPS2222A	ICEX	_	10	nAdc
Collector Cutoff Current (V <sub>CB</sub> = 50 Vdc, I <sub>E</sub> = 0) (V <sub>CB</sub> = 60 Vdc, I <sub>E</sub> = 0) (V <sub>CB</sub> = 50 Vdc, I <sub>E</sub> = 0, T <sub>A</sub> = 125°C) (V <sub>CB</sub> = 50 Vdc, I <sub>E</sub> = 0, T <sub>A</sub> = 125°C)	MPS2222 MPS2222A MPS2222 MPS2222A	ІСВО	_ _ _ _	0.01 0.01 10 10	μAdc
Emitter Cutoff Current (VEB = 3.0 Vdc, I <sub>C</sub> = 0)	MPS2222A	I <sub>EBO</sub>	_	100	nAdc
Base Cutoff Current (VCE = 60 Vdc, VEB(off) = 3.0 Vdc)	MPS2222A	I <sub>BL</sub>	_	20	nAdc

Preferred devices are Motorola recommended choices for future use and best overall value.



\*Motorola Preferred Device





## MPS2222 MPS2222A

## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

Characteristic			Symbol	Min	Max	Unit
ON CHARACTERI	STICS					-
DC Current Gain (I <sub>C</sub> = 0.1 mAdc, V <sub>C</sub> ) (I <sub>C</sub> = 1.0 mAdc, V <sub>C</sub> ) (I <sub>C</sub> = 10 mAdc, V <sub>C</sub> ) (I <sub>C</sub> = 10 mAdc, V <sub>C</sub> ) (I <sub>C</sub> = 150 mAdc, V <sub>C</sub> )	CE = 10 Vdc) CE = 10 Vdc) CE = 10 Vdc, T <sub>A</sub> = -55°C)	MPS2222A only	hFE	35 50 75 35 100	    300	_
(IC = 150 mAdc, V (IC = 500 mAdc, V	CE = 1.0  Vdc	MPS2222 MPS2222A		50 30 40	— — — —	
Collector-Emitter Sa (I <sub>C</sub> = 150 mAdc, I <sub>E</sub>		MPS2222 MPS2222A	VCE(sat)	=	0.4 0.3	Vdc
$(I_C = 500 \text{ mAdc}, I_E)$	3 = 50 mAdc)	MPS2222 MPS2222A		_	1.6 1.0	
Base-Emitter Satura (I <sub>C</sub> = 150 mAdc, I <sub>E</sub>		MPS2222 MPS2222A	V <sub>BE</sub> (sat)	 0.6	1.3 1.2	Vdc
$(I_C = 500 \text{ mAdc}, I_E)$	<sub>3</sub> = 50 mAdc)	MPS2222 MPS2222A		_	2.6 2.0	
SMALL-SIGNAL (	CHARACTERISTICS				•	
Current-Gain — Ba (I <sub>C</sub> = 20 mAdc, V <sub>C</sub>	ndwidth Product <sup>(2)</sup> E = 20 Vdc, f = 100 MHz)	MPS2222 MPS2222A	fΤ	250 300		MHz
Output Capacitance (V <sub>CB</sub> = 10 Vdc, I <sub>E</sub>	= 0, f = 1.0 MHz)		C <sub>obo</sub>	_	8.0	pF
Input Capacitance (V <sub>EB</sub> = 0.5 Vdc, I <sub>C</sub>	c = 0, f = 1.0 MHz)	MPS2222 MPS2222A	C <sub>ibo</sub>	_	30 25	pF
	CE = 10 Vdc, f = 1.0 kHz) CE = 10 Vdc, f = 1.0 kHz)	MPS2222A MPS2222A	h <sub>ie</sub>	2.0 0.25	8.0 1.25	kΩ
Voltage Feedback R (I <sub>C</sub> = 1.0 mAdc, V <sub>C</sub> (I <sub>C</sub> = 10 mAdc, V <sub>C</sub>	atio CE = 10 Vdc, f = 1.0 kHz) E = 10 Vdc, f = 1.0 kHz)	MPS2222A MPS2222A	h <sub>re</sub>	_ _	8.0 4.0	X 10 <sup>-4</sup>
	nt Gain CE = 10 Vdc, f = 1.0 kHz) CE = 10 Vdc, f = 1.0 kHz)	MPS2222A MPS2222A	h <sub>fe</sub>	50 75	300 375	_
	CE = 10 Vdc, f = 1.0 kHz) CE = 10 Vdc, f = 1.0 kHz)	MPS2222A MPS2222A	h <sub>oe</sub>	5.0 25	35 200	μmhos
Collector Base Time (I <sub>E</sub> = 20 mAdc, V <sub>C</sub>	Constant c <sub>B</sub> = 20 Vdc, f = 31.8 MHz)	MPS2222A	rb′C <sub>C</sub>	_	150	ps
Noise Figure (I <sub>C</sub> = 100 μAdc, V <sub>0</sub>	CE = 10 Vdc, R <sub>S</sub> = 1.0 kΩ, f = 1.0 kHz	r) MPS2222A	NF	_	4.0	dB
SWITCHING CHAF	RACTERISTICS MPS2222A on	ly				
Delay Time	$(V_{CC} = 30 \text{ Vdc}, V_{BE(off)} = -0.5 \text{ Vdc})$		t <sub>d</sub>	_	10	ns
Rise Time	I <sub>C</sub> = 150 mAdc, I <sub>B1</sub> = 15 mAdc) (Fi	gure 1)	t <sub>r</sub>	_	25	ns
Storage Time	$(V_{CC} = 30 \text{ Vdc}, I_{C} = 150 \text{ mAdc}, I_{B1} = I_{B2} = 15 \text{ mAdc}) \text{ (Figure 2)}$		t <sub>S</sub>		225	ns
Fall Time	101 - 102 - 10 111/100) (1 Igule 2)		t <sub>f</sub>	_	60	ns

<sup>1.</sup> Pulse Test: Pulse Width  $\leq 300~\mu s$ , Duty Cycle  $\leq 2.0\%$ . 2. f<sub>T</sub> is defined as the frequency at which  $|h_{fe}|$  extrapolates to unity.

### **SWITCHING TIME EQUIVALENT TEST CIRCUITS**

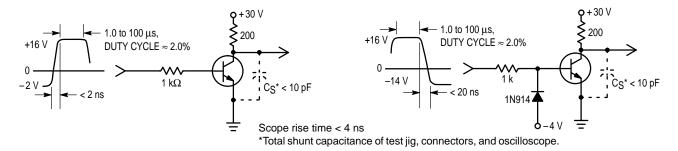


Figure 1. Turn-On Time

Figure 2. Turn-Off Time

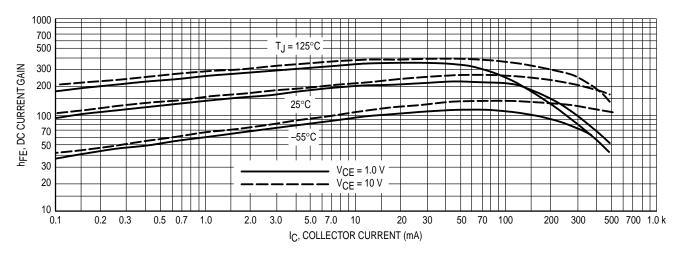


Figure 3. DC Current Gain

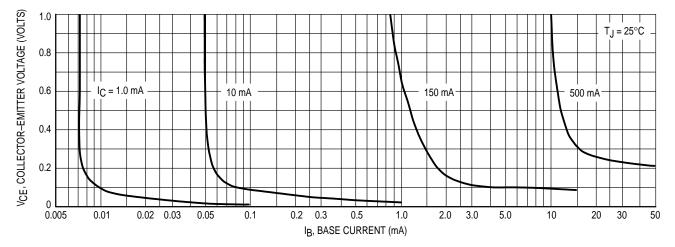


Figure 4. Collector Saturation Region

#### **MPS2222 MPS2222A**

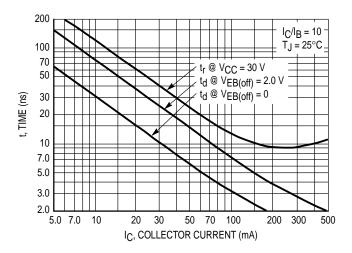
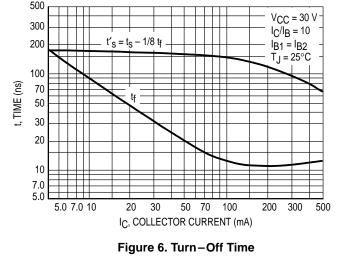


Figure 5. Turn-On Time



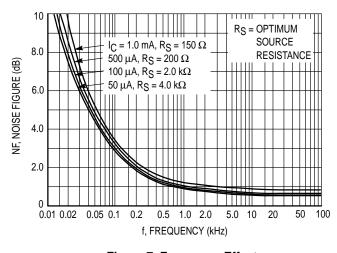


Figure 7. Frequency Effects

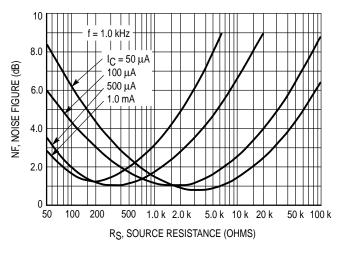


Figure 8. Source Resistance Effects

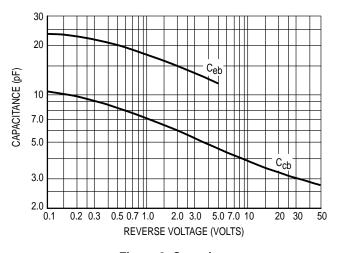


Figure 9. Capacitances

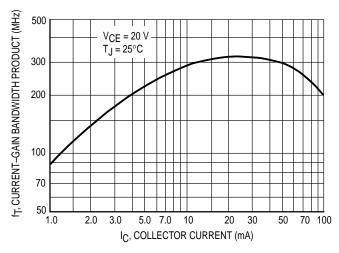


Figure 10. Current-Gain Bandwidth Product

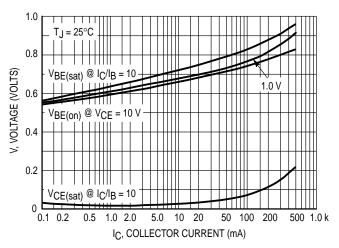


Figure 11. "On" Voltages

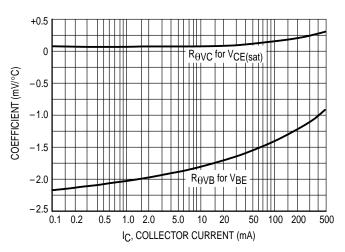
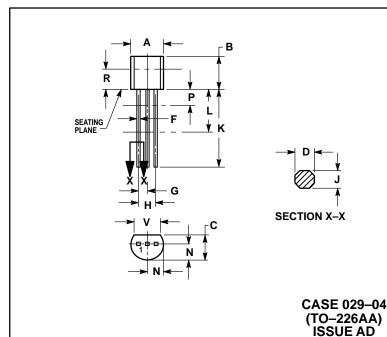


Figure 12. Temperature Coefficients

#### PACKAGE DIMENSIONS



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- DIMENSION F APPLIES BETWEEN P AND L DIMENSION F APPLIES BETWEEN F AND L.
  DIMENSION D AND J APPLY BETWEEN L AND K
  MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	

STYLE 1:

PIN 1. EMITTER

BASE 3. COLLECTOR

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